



NSS40200UW6T1G Information



For Reference Only

Part Number NSS40200UW6T1G Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

6-WDFN Exposed Pad

Transistors - Bipolar (BJT) - Single

Description TRANS PNP 40V 2A 6-WDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

Package









NSS40200UW6T1G Specifications

Manufacturer Part Number	NSS40200UW6T1G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	6-WDFN Exposed Pad
Series	-
Transistor Type	PNP
Current - Collector (Ic) (Max)	2A
Voltage - Collector Emitter Breakdown (Max)	40V
Vce Saturation (Max) @ Ib, Ic	300mV @ 20mA, 2A
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	150 @ 1A, 2V
Power - Max	875mW
Frequency - Transition	140MHz
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	6-WDFN Exposed Pad
Supplier Device Package	6-WDFN (2x2)
	Report errors?

NSS40200UW6T1G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NSS40200UW6T1G Payment Methods



















NSS40200UW6T1G Shipping Methods













If you have any question about NSS40200UW6T1G, please do not hesitate to contact us!

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